

SANYO Semiconductors DATA SHEET

N-Channel Silicon Junction FET

MCH5908 — High-Frequency Amplifier, AM Amplifier, Low-Frequency Amplifier Applications

Features

- Composite type with 2 J-FET contained in a MCPH5 package currently in use, improving the mounting efficiency greatly.
- The MCH5908 is formed with two chips, being equivalent to the 2SK3557, placed in one package.

Specifications

Absolute Maximum Ratings at Ta=25°C

Parameter	Symbol	Conditions	Ratings	Unit
Drain-to-Source Voltage	VDSX		15	V
Gate-to-Drain Voltage	V _{GDS}		-15	V
Gate Voltage	IG		10	mA
Drain Current	ID		50	mA
Allowable Power Dissipation	PD	1 unit	200	mW
Total Power Dissipation	PT		300	mW
Junction Temperature	Tj		150	°C
Storage Temperature	Tstg		-55 to +150	°C

Electrical Characteristics at Ta=25°C

Parameter Sym	Cumahal	Conditions	Ratings			Lloit
	Symbol		min	typ	max	Unit
Gate-to-Drain Breakdown Voltage	V(BR)GDS	IG=-10μA, VDS=0V	-15			V
Gate-to-Source Leakage Current	IGSS	V _{GS} =-10V, V _{DS} =0V			-1.0	nA
Cutoff Voltage	VGS(off)	V _{DS} =5V, I _D =100μA	-0.3	-0.7	-1.5	V
Drain Current	IDSS	V _{DS} =5V, V _{GS} =0V	10.0*		32.0*	mA

The specifications shown above are for each individual J-FET.

Continued on next page.

*: The MCH5908 is classified by IDSS as follows (unit: mA).							
Marking	KG	KH					
Rank	G	Н					
I _{DSS} (mA)	10 to 20	16 to 32					

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SANYO Semiconductor Co., Ltd.

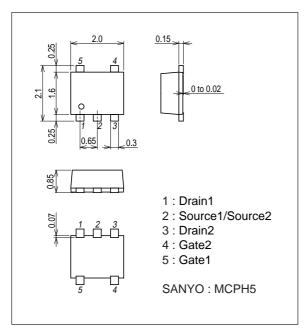
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Parameter	Symbol	Conditions	Ratings			Unit
i alametei	Symbol		min	typ	max	Offic
Forward Transfer Admittance	yfs	V _{DS} =5V, V _{GS} =0V, f=1kHz	24	35		mS
Input Capacitance	Ciss	V _{DS} =5V, V _{GS} =0V, f=1MHz		10.5		pF
Reverse Transfer Capacitance	Crss	V _{DS} =5V, V _{GS} =0V, f=1MHz		3.5		pF
Noise Figure	NF	VDS=5V, Rg=1kΩ, ID=1mA, f=1kHz		1.0		dB

Package Dimensions

unit : mm (typ) 7021A-009



Marking

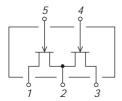


1 : Drain1

2: Source1/Source2

3 : Drain2 4 : Gate2 5 : Gate1

Electrical Connection

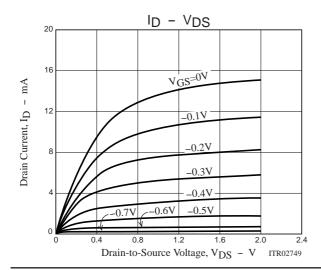


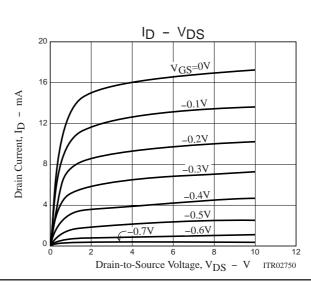
1 : Drain1

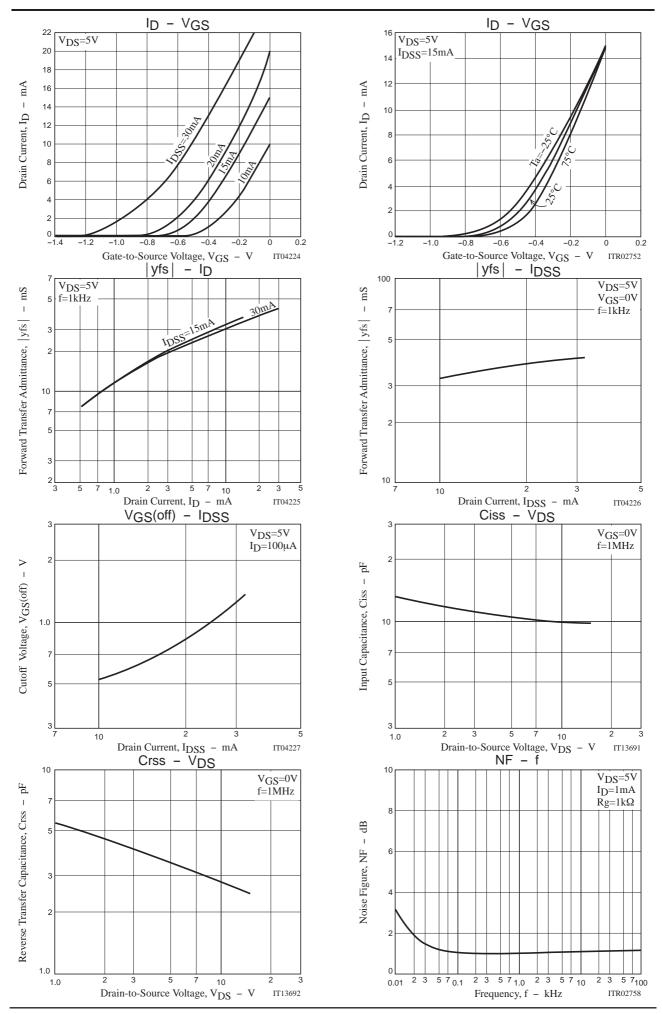
2: Source1/Source2

3 : Drain2 4 : Gate2 5 : Gate1

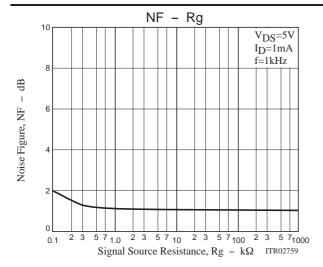
Top view

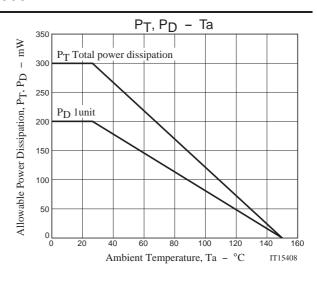






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